TinyLogic UHS 2-Input NAND Gate, Open Drain Output NC7SZ38

Description

The NC7SZ38 is a single 2–Input NAND gate with open drain output stage from **onsemi**'s Ultra–High Speed Series of TinyLogic. The device is fabricated with advanced CMOS technology to achieve ultra–high speed with high output drive while maintaining low static power dissipation over a very broad V_{CC} operating range. The device is specified to operate over the 1.65 V to 5.5 V V_{CC} range. The inputs and output are high impedance when V_{CC} is 0 V. Inputs tolerate voltages up to 5.5 V, independent of V_{CC} when in the high impedance state. The open drain output stage tolerates voltages up to 6 V independent of V_{CC} when in the high impedance state.

Features

- Ultra-High Speed: $t_{PD} = 2.2 \text{ ns}$ (Typical) into 50 pF at 5 V V_{CC}
- Open Drain Output Stage for OR Tied Applications
- High Output Sink Drive: ±24 mA at 3 V V_{CC}
- Broad V_{CC} Operating Range: 1.65 V to 5.5 V
- $\bullet\,$ Matches Performance of LCX Operated at 3.3 V V_{CC}
- Power Down High-Impedance Inputs / Outputs
- Over-Voltage Tolerance Inputs Facilitate 5 V to 3 V Translation
- Proprietary Noise / EMI Reduction Circuitry
- Ultra−Small MicroPak™ Packages
- Space-Saving SC-74A and SC-88A Packages
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

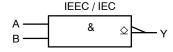
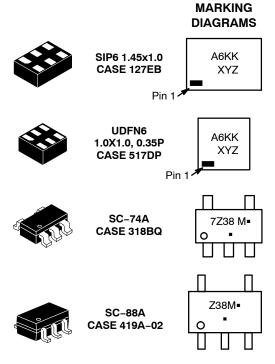


Figure 1. Logic Symbol

1



A6, 7Z38, Z38 = Specific Device Code

KK = 2-Digit Lot Run Traceability Code

XY = 2-Digit Date Code Format Z = Assembly Plant Code

M = Data Code*
= Pb−Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

Pin Configurations

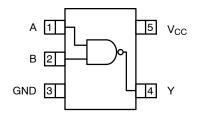


Figure 2. SC-88A and SC-74A (Top View)

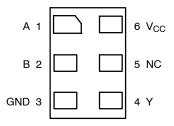


Figure 3. MicroPak (Top Through View)

PIN DEFINITIONS

Pin # SC-88A / SC-74A	Pin # MicroPak	Name	Description
1	1	Α	Input
2	2	В	Input
3	3	GND	Ground
4	4	Υ	Output
5	6	V _{CC}	Supply Voltage
	5	NC	No Connect

FUNCTION TABLE

Inp	Output	
Α	В	Υ
L	L	*H
L	Н	*H
Н	L	*H
Н	Н	L

H = HIGH Logic Level L = LOW Logic Level *H = High Impedance Output State, Open Drain

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		Min	Max	Unit
V _{CC}	Supply Voltage		-0.5	6.5	V
V _{IN}	DC Input Voltage		-0.5	6.5	V
V _{OUT}	DC Output Voltage		-0.5	6.5	V
I _{IK}	DC Input Diode Current	V _{IN} < 0 V	-	-50	mA
I _{OK}	DC Output Diode Current	V _{OUT} < 0 V	-	-50	mA
I _{OUT}	DC Output Current		-	±50	mA
I _{CC} or I _{GND}	DC V _{CC} or Ground Current		-	±50	mA
T _{STG}	Storage Temperature Range		-65	+150	°C
TJ	Junction Temperature Under Bias		-	+150	°C
TL	Junction Lead Temperature (Solder	ring, 10 Seconds)	-	+260	°C
P_{D}	Power Dissipation in Still Air	SC-74A	-	390	mW
		SC-88A	-	332	
		MicroPak-6	-	812	
		MicroPak2™-6	-	812	
ESD	Human Body Model, JEDEC: JESD22-A114		-	4000	V
	Charge Device Model, JEDEC: JES	SD22-C101	-	2000	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage Operating		1.65	5.5	V
	Supply Voltage Data Retention		1.50	5.5	
V _{IN}	Input Voltage		0	5.5	V
V _{OUT}	Output Voltage		0	5.5	V
T _A	Operating Temperature		-40	+85	°C
t _r , t _f	Input Rise and Fall Times	V _{CC} = 1.8 V, 2.5 V ±0.2 V	0	20	ns/V
		V _{CC} = 3.3 V ±0.3 V	0	10	
		V _{CC} = 5.0 V ±0.5 V	0	5	
$\theta_{\sf JA}$	Thermal Resistance	SC-74A	=	320	°C/W
		SC-88A	=	377	
		MicroPak-6	-	154	
		MicroPak2-6	-	154	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. Unused inputs must be held HIGH or LOW. They may not float.

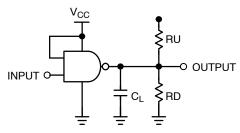
DC ELECTICAL CHARACTERISTICS

			$T_A = +25^{\circ}C$ $T_A = -4$		T _A = -40	to +85°C			
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
V _{IH}	HIGH Level Input Voltage	1.65 to 1.95		0.65 V _{CC}	-	-	0.65 V _{CC}	-	V
		2.30 to 5.50		0.70 V _{CC}	-	-	0.70 V _{CC}	-	
V _{IL}	LOW Level Input Voltage	1.65 to 1.95		-	-	0.35 V _{CC}	-	0.35 V _{CC}	V
		2.30 to 5.50		-	-	0.30 V _{CC}	-	0.30 V _{CC}	
I _{LKG}	HIGH Level Output Leakage	5.50	$V_{IN} = V_{IL},$ $V_{OUT} = V_{CC}$ or GND	-	-	±5	-	±10	μΑ
V _{OL}	LOW Level Output Voltage	1.65 $V_{IN} = V_{IH} \text{ or } V_{IL}$	-	0.00	0.10	-	0.10	V	
		1.80	l _{OL} = 100 μA	_	0.00	0.10	-	0.10	
		2.30		_	0.00	0.10	-	0.10	
		3.00		_	0.00	0.10	-	0.10	
		4.50		-	0.00	0.10	-	0.10	1
		1.65	I _{OL} = 4 mA	-	0.80	0.24	-	0.24	1
		2.30	I _{OL} = 8 mA	-	0.10	0.30	-	0.30	
		3.00	I _{OL} = 16 mA	-	0.15	0.40	-	0.40	
		3.00	I _{OL} = 24 mA	-	0.22	0.55	-	0.55	
		4.50	I _{OL} = 32 mA	-	0.22	0.55	-	0.55	
I _{IN}	Input Leakage Current	5.50	V _{IN} = 5.5 V, GND	-	-	±1	-	±10	μΑ
I _{OFF}	Power Off Leakage Current	0	V _{IN} or V _{OUT} = 5.5 V	-	-	1	-	10	μΑ
I _{CC}	Quiescent Supply Current	5.50	V _{IN} = 5.5 V, GND	-	-	2	_	20	μΑ

AC ELECTRICAL CHARACTERISTICS

				7	Γ _A = +25°C	;	T _A = -40	to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
t _{PZL}	Propagation Delay	1.65	C _L = 50 pF,	-	6.5	12.7	-	13.2	ns
	(Figure 4, 5)	1.80	RU = 500 Ω , RD = 500 Ω ,	-	5.4	10.5	-	11.0	
		2.50 ±0.20	$V_{IN} = 2 \cdot V_{CC}$	-	3.5	7.0	-	7.5	
		3.30 ±0.30		-	2.8	5.0	-	5.2	
		5.00 ±0.50		-	2.2	4.3	-	4.5	
t _{PLZ}		1.65	C _L = 50 pF,	-	5.5	12.7	-	13.2	ns
		1.80	RU = 500Ω , RD = 500Ω , $V_{IN} = 2 \cdot V_{CC}$	-	4.6	10.5	-	11.0	
		2.50 ±0.20		-	3.0	7.0	-	7.5	
		3.30 ±0.30		-	2.1	6.0	-	5.2	
		5.00 ±0.50		-	1.3	4.3	-	4.5	
C _{IN}	Input Capacitance	0.00		-	4.0	-	-	-	pF
C _{OUT}	Output Capacitance	0.00		-	5.0	-	-	-	pF
C _{PD}	C _{PD} Power Dissipation Capacitance	3.30		-	5.1	-	-	-	pF
	(Note 2) (Figure 6)		1	-	7.3	_	-	_	

^{2.} C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CC}static).



NOTE:

3. CL includes load and stray capacitance. Input PRR = 10 MHz $t_{\rm W}$ = 500 ns.

Figure 4. AC Test Circuit

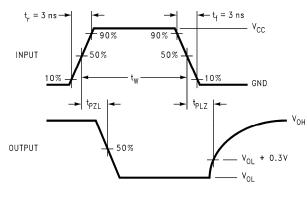
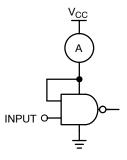


Figure 5. AC Waveforms



NOTE:

4. Input = AC Waveform; $t_r = t_f = 1.8 \text{ ns}$; PRR = 10 MHz; Duty Cycle = 50%.

Figure 6. Test Circuit

DEVICE ORDERING INFORMATION

Device	Top Mark	Packages	Shipping [†]
NC7SZ38M5X	7Z38	5-Lead SC-74A, 1.6mm	3000 / Tape & Reel
NC7SZ38P5X	Z38	5-Lead SC70, EIAJ SC-88a, 1.25 mm Wide	3000 / Tape & Reel
NC7SZ38P5X-L22057	Z38	5-Lead SC70, EIAJ SC-88a, 1.25 mm Wide	3000 / Tape & Reel
NC7SZ38L6X	A6	6-Lead MicroPak, 1.00 mm Wide	5000 / Tape & Reel
NC7SZ38FHX	A6	6-Lead, MicroPak2, 1 x 1 mm Body, 0.35 mm Pitch	5000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MicroPak is trademark of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries.



DATE 31 AUG 2016



NOTES:

- 1. CONFORMS TO JEDEC STANDARD MO-252 VARIATION UAAD
- 2. DIMENSIONS ARE IN MILLIMETERS
- 3. DRAWING CONFORMS TO ASME Y14.5M-2009
 4. PIN ONE IDENTIFIER IS 2X LENGTH OF ANY

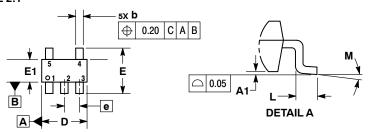
 - OTHER LINE IN THE MARK CODE LAYOUT.

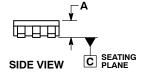
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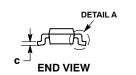
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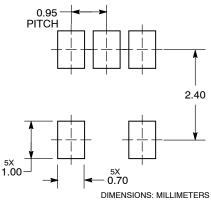
DATE 18 JAN 2018







RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NOTES:

- DIMENSIONING AND TOLERANCING PER ASME
 Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
 THICKNESS. MINIMUM LEAD THICKNESS IS THE
 MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.

	MILLIMETERS			
DIM	MIN	MAX		
Α	0.90	1.10		
A1	0.01	0.10		
b	0.25 0.50			
С	0.10	0.26		
D	2.85	3.15		
E	2.50	3.00		
E1	1.35	1.65		
е	0.95 BSC			
L	0.20	0.60		
М	0 °	10°		

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

Μ = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ", may or may not be present. Some products may not follow the Generic Marking.

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SC-88A (SC-70-5/SOT-353) CASE 419A-02 **ISSUE L**

DATE 17 JAN 2013



- TES:
 DIMENSIONING AND TOLERANCING
 PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 419A-01 OBSOLETE. NEW STANDARD 3.
- 419A-02.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
С	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026	BSC	0.65 BSC	
Н		0.004		0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20	REF
S	0.079	0.087	2 00	2 20





XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



0.50 0.0197 0.65 0.025 0.65 0.025 0.40 0.0157 1.9 mm 0.0748 SCALE 20:1

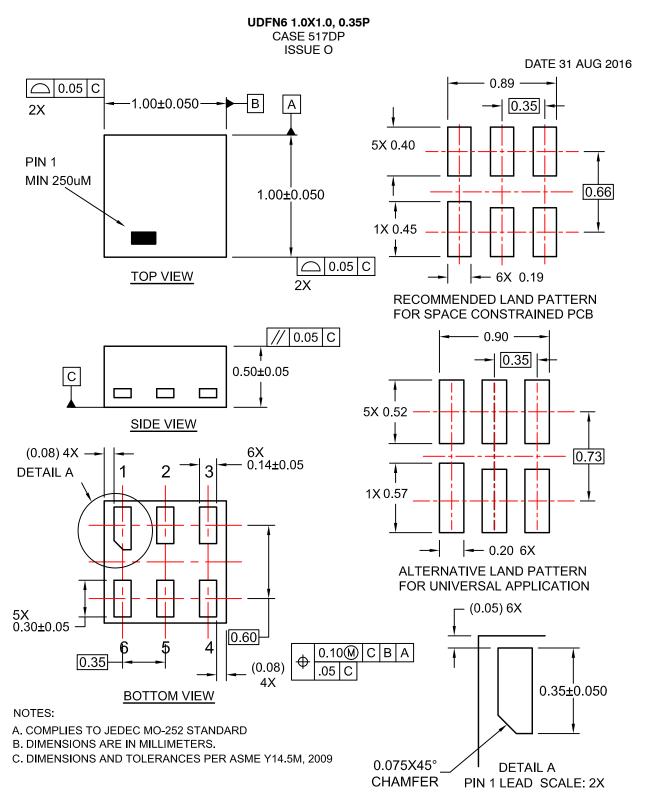
SOLDER FOOTPRINT

STYLE 1: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR	STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR	STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2	STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3. SOURCE 1 4. GATE 1	STYLE 5: PIN 1. CATHODE 2. COMMON ANODE 3. CATHODE 2 4. CATHODE 3
5. COLLECTOR	5. CATHODE	5. CATHODE 1	5. GATE 2	5. CATHODE 4

5. COLLECTOR	5. CATHODE	5. CATHODE 1	4. GATE 1 5. GATE 2	5. CATHODE 3
STYLE 6:	STYLE 7:	STYLE 8:	STYLE 9:	Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.
PIN 1. EMITTER 2	PIN 1. BASE	PIN 1. CATHODE	PIN 1. ANODE	
2. BASE 2	2. EMITTER	2. COLLECTOR	2. CATHODE	
3. EMITTER 1	3. BASE	3. N/C	3. ANODE	
4. COLLECTOR	4. COLLECTOR	4. BASE	4. ANODE	
5. COLLECTOR 2/BASE 1	5. COLLECTOR	5. EMITTER	5. ANODE	

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